MAU2D30

Silicon epitaxial planar type

For high speed switching circuits

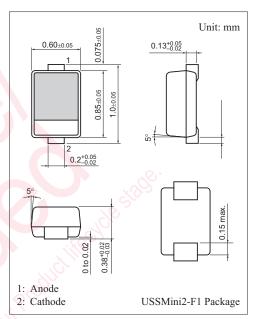
■ Features

- Optimum for high-density mounting
- Extremely low reverse current I_R
- Short reverse recovery time t_{rr}

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Reverse voltage	V_R	30	V	
Repetitive peak reverse voltage	V _{RRM}	30	V	
Forward current (Average)	I _{F(AV)}	100	mA	
Peak forward current	I_{FM}	200	mA	
Non-repetitive peak forward surge current *	I_{FSM}	1	A	
Junction temperature	Tj	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	

Note) *: 50 Hz sine wave 1 cycle (Non-repetitive peak current)



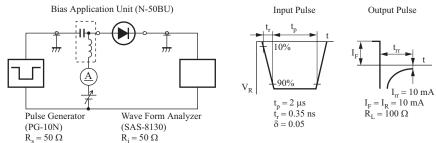
Marking Symbol: 1D

■ Electrical Characteristics $T_a = 25$ °C±3°C

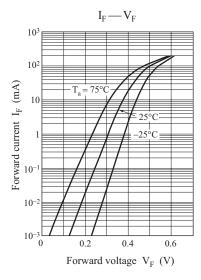
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V_{F1}	$I_F = 10 \text{ mA}$	5 1918	0.38	0.44	V
	V_{F2}	$I_F = 100 \text{ mA}$		0.51	0.58	V
Reverse current	I_{R1}	$V_R = 10 \text{ V}$),	0.3	μΑ
	I_{R2}	$V_R = 30 \text{ V}$	03/1		2	μΑ
Terminal capacitance	C _t	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$		9		pF
Reverse recovery time *	t _{rr}	$\begin{aligned} I_F &= I_R = 10 \text{ mA}, \ I_{rr} = 10 \text{ mA}, \\ R_L &= 100 \ \Omega \end{aligned}$		1		ns

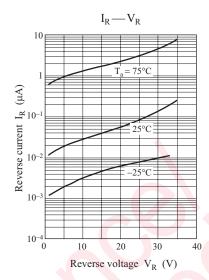
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

- 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
- 3. Absolute frequency of input and output is 250 MHz
- 4. *: t_{rr} measurement circuit

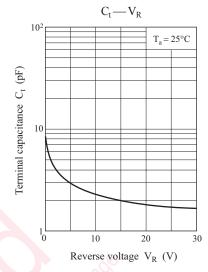


MAU2D30 Panasonic





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